Ordering number : ENN8251



SANYO Semiconductors DATA SHEET

2SC6044

NPN Epitaxial Planar Silicon Transistors

High-Current Switching Applications

Applications

· Voltage regulators, relay drivers, lamp drivers, electrical equipment.

Features

- · Adoption of MBIT process.
- · Low collector-to-emitter saturation voltage.
- · High current capacity.
- · High-speed switching.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	Vcво		40	٧
Collector-to-Emitter Voltage	VCEO		30	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		2	Α
Collector Current (Pulse)	ICP		5	Α
Base Current	IΒ	4 to 6 to 6	400	mA
Collector Dissipation	D-	Mounted on a ceramic board (450mm²X0.8mm)	1.3	W
	PC	Tc=25°C	3.5	W
Junction Temperature	Tj	- FRI 60 -	150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Cumbal	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =30V, I _E =0			0.1	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0	140	-	0.1	μΑ
DC Current Gain	hFE1	V _{CE} =2V, I _C =100mA	200	12 - T	560	COT
	hFE2	V _{CE} =2V, I _C =1.5A	65	100	Ora-	
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =300mA		400		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		12		pF

Marking: HB

Continued on next page.

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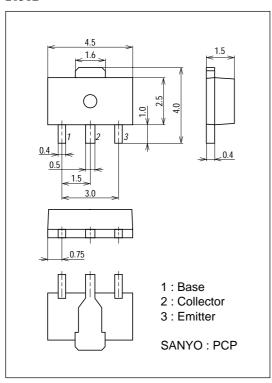
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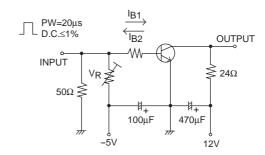
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C =1.5A, I _B =75mA		170	260	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =1.5A, I _B =75mA		0.94	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μA, I _E =0	40			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	30			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =10μA, I _C =0	5			V
Turn-ON Time	ton	See specified Test Circuit.		40		ns
Storage Time	tstg	See specified Test Circuit.		350		ns
Fall Time	tf	See specified Test Circuit.		30		ns

Package Dimensions

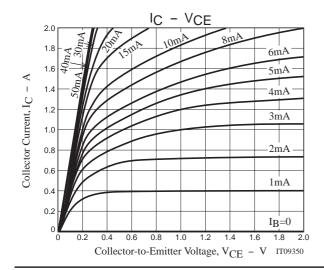
unit : mm 2038B

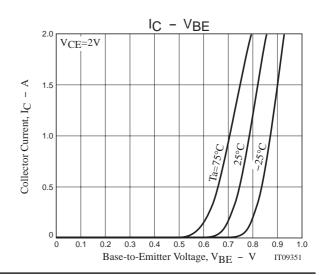


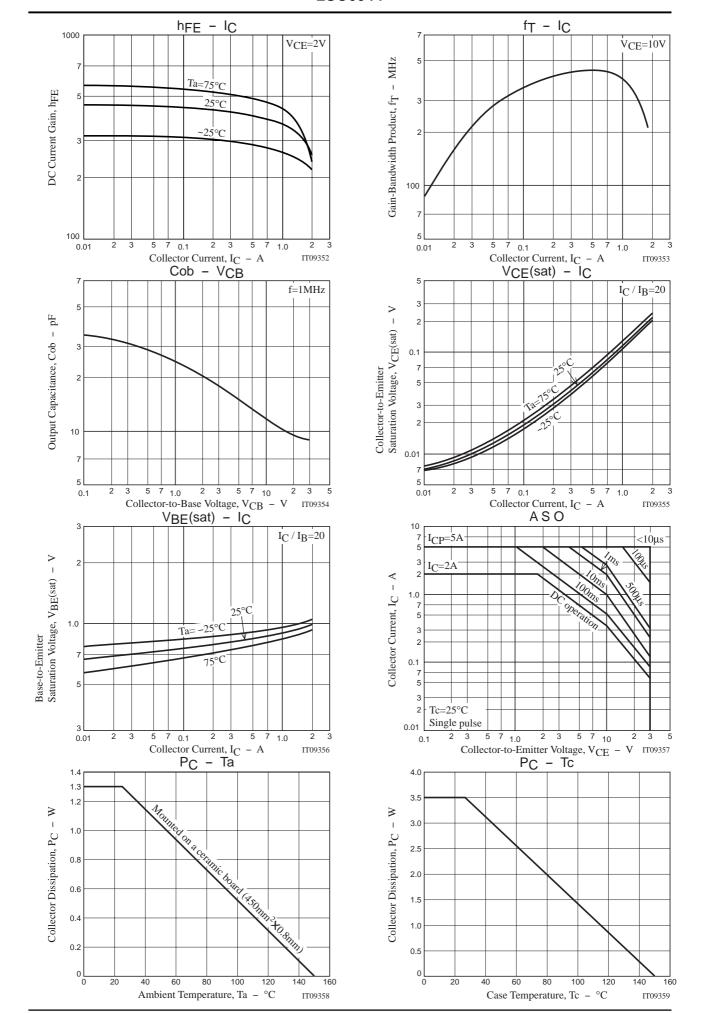
Switching Time Test Circuit



 $20I_{B1} = -20I_{B2} = I_C = 500mA$







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